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September 1999



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FDS9431A

P-Channel 2.5V Specified MOSFET

General Description

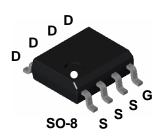
This P-Channel 2.5V specified MOSFET is produced using ON Semiconductor's proprietary, high cell density, DMOS technology. This very high density process has been especially tailored to minimize onstate resistance and yet maintain superior switching performance.

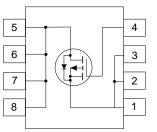
Applications

- DC/DC converter
- Power management
- · Load switch
- Battery protection

Features

- -3.5 A, -20 V. $R_{DS(ON)} = 0.130 \ \Omega \ @ V_{GS} = -4.5 \ V$ $R_{DS(ON)} = 0.180 \ \Omega \ @ V_{GS} = -2.5 \ V.$
- Fast switching speed.
- High density cell design for extremely low R_{DS(ON)}.
- High power and current handling capability.





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-20	V
V _{GSS}	Gate-Source Voltage		±8	V
ID	Drain Current - Continuous	(Note 1a)	-3.5	A
	- Pulsed		-18	
P _D	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.2	
		(Note 1c)	1.0	
T _J , T _{stg}	Operating and Storage Junction Temperat	ure Range	-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS9431A	FDS9431A	13"	12mm	2500 units

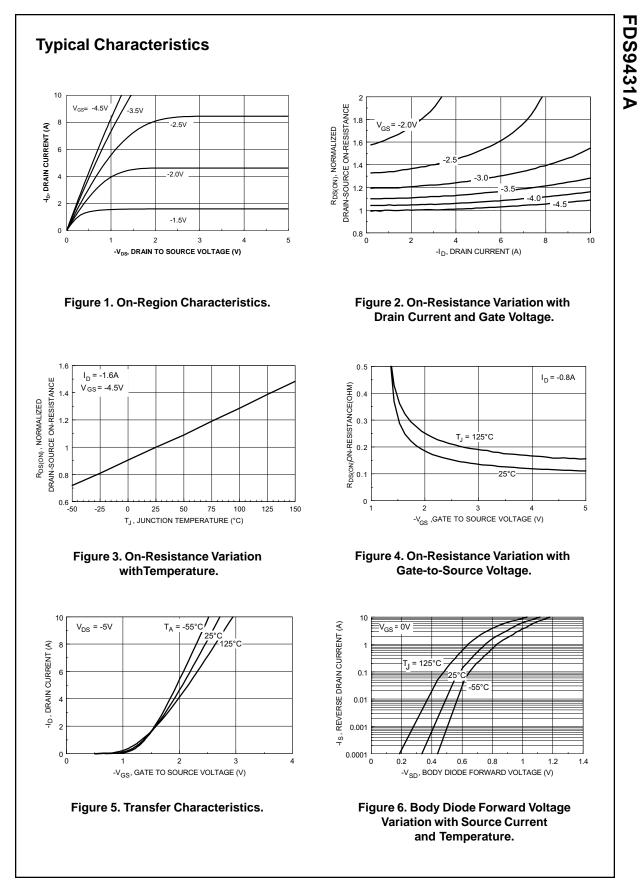
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Publication Order Number: FDS9431A/D

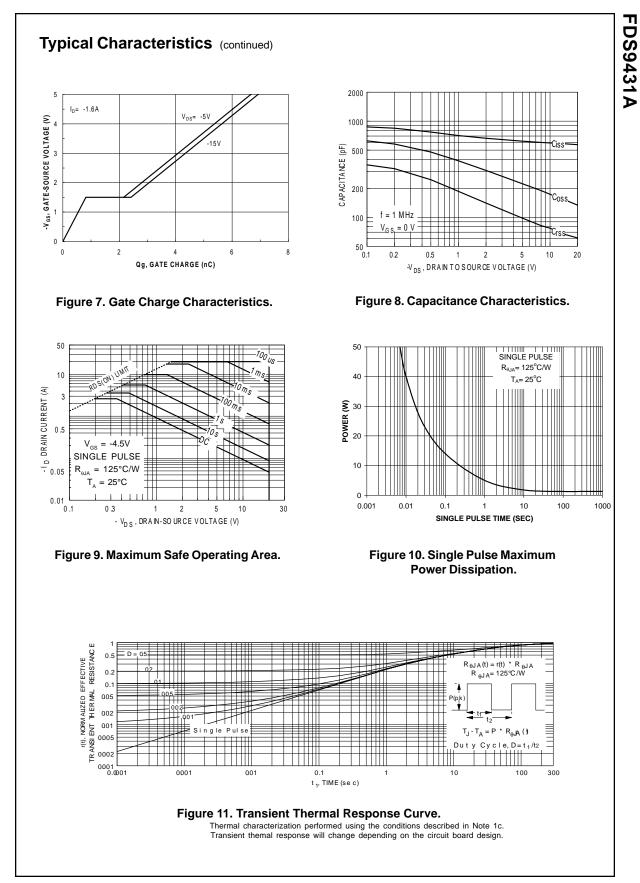
Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A,Referenced to 25°C		-28		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16$ V, $V_{GS} = 0$ V			-1	μA
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$			100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	-0.4	-0.6	-1	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = -250 µA,Referenced to 25°C		2		mV/°C
R _{DS(on)}	Static Drain-Source	$V_{GS} = -4.5 \text{ V}, I_D = -3.5 \text{ A}$		0.110	0.130	Ω
	On-Resistance	V _{GS} = -2.5 V, I _D = -3.0 A V _{GS} = -4.5 V, I _D = -3.5 A		0.140	0.180 0.220	Ω
		T _J =125°C		0.155	0.220	Ω
D(on)	On-State Drain Current	V _{GS} = -4.5 V, V _{DS} =-5 V	-10			А
g _{FS}	Forward Transconductance	$V_{DS} = -5 V, I_D = -3.5 A$		6.5		S
Dynamic	Characteristics	-				
Ciss	Input Capacitance	$V_{DS} = -10 V, V_{GS} = 0 V,$		405		pF
Coss	Output Capacitance	f = 1.0 MHz		170		pF
C _{rss}	Reverse Transfer Capacitance	-		45		pF
Switchin	g Characteristics (Note 2)	•	-			
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -5 V, I_D = -1 A,$		6.5	13	ns
tr	Turn-On Rise Time	$V_{GS} = -4.5 V, R_{GEN} = 6 \Omega$		20	35	ns
t _{d(off)}	Turn-Off Delay Time	7		31	50	ns
t _f	Turn-Off Fall Time	-		21	35	ns
Qg	Total Gate Charge	$V_{DS} = -5 V, I_D = -3.5 A,$		6	8.5	nC
Q _{gs}	Gate-Source Charge	V _{GS} = -4.5 V		0.8		nC
Q _{gd}	Gate-Drain Charge	-		1.3		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source				-2.1	А
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_S = -2.1 A$ (Note 2)		-0.7	-1.2	V
	n of the junction-to-case and case-to-ambient therma $_{\rm C}$ is guaranteed by design while ${\rm R}_{\rm \theta CA}$ is determined b		ined as the	<u>_</u>		e of the

FDS9431A

2: Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%



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